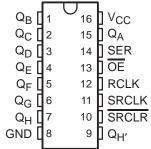
- EPIC™ (Enhanced-Performance Implanted CMOS) Process
- Typical V_{OLP} (Output Ground Bounce)
 <0.8 V at V_{CC} = 3.3 V, T_A = 25°C
- Typical V_{OHV} (Output V_{OH} Undershoot)
 >2.3 V at V_{CC} = 3.3 V, T_A = 25°C
- 2-V to 5.5-V V_{CC} Operation
- Support Mixed-Mode Voltage Operation on All Ports
- 8-Bit Serial-In, Parallel-Out Shift
- Shift Register Has Direct Clear
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- ESD Protection Exceeds 2000 V Per MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)
- Package Options Include Plastic Small-Outline (D, NS), Shrink Small-Outline (DB), and Thin Shrink Small-Outline (PW) Packages, Ceramic Flat (W) Packages, Chip Carriers (FK), and DIPs (J)

description

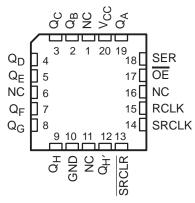
The 'LV595A devices are 8-bit shift registers designed for 2-V to 5.5-V V_{CC} operation.

These devices contain an 8-bit serial-in, parallel-out shift register that feeds an 8-bit D-type

SN54LV595A . . . J OR W PACKAGE SN74LV595A . . . D, DB, NS, OR PW PACKAGE (TOP VIEW)



SN54LV595A . . . FK PACKAGE (TOP VIEW)



NC - No internal connection

storage register. The storage register has parallel 3-state outputs. Separate clocks are provided for both the shift and storage register. The shift register has a direct overriding clear (\overline{SRCLR}) input, serial (SER) input, and a serial output for cascading. When the output-enable (\overline{OE}) input is high, all outputs except $Q_{H'}$ are in the high-impedance state.

Both the shift register clock (SRCLK) and storage register clock (RCLK) are positive-edge triggered. If both clocks are connected together, the shift register always is one clock pulse ahead of the storage register.

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

The SN54LV595A is characterized for operation over the full military temperature range of –55°C to 125°C. The SN74LV595A is characterized for operation from –40°C to 85°C.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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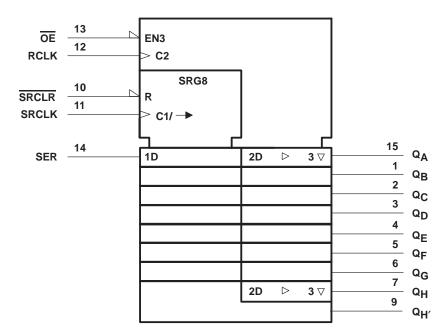


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FUNCTION TABLE

		INPUTS			FUNCTION
SER	SRCLK	SRCLR	RCLK	OE	FUNCTION
Х	Х	Х	Х	Н	Outputs Q _A –Q _H are disabled.
X	X	X	Χ	L	Outputs Q _A –Q _H are enabled.
Х	Χ	L	Χ	Χ	Shift register is cleared.
L	1	Н	Х	Х	First stage of the shift register goes low. Other stages store the data of previous stage, respectively.
Н	1	Н	Х	Х	First stage of the shift register goes high. Other stages store the data of previous stage, respectively.
Х	\downarrow	Н	Х	Х	Shift-register state is not changed.
Х	Χ	X	\uparrow	Χ	Shift-register data is stored in the storage register.
Х	Х	X	\downarrow	Х	Storage-register state is not changed.

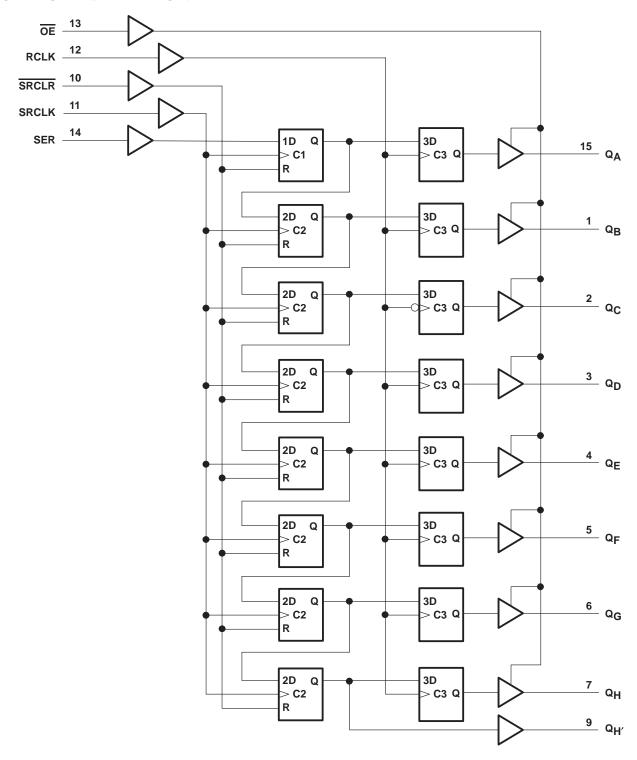
logic symbol†



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12. Pin numbers shown are for the D, DB, J, NS, PW, and W packages.



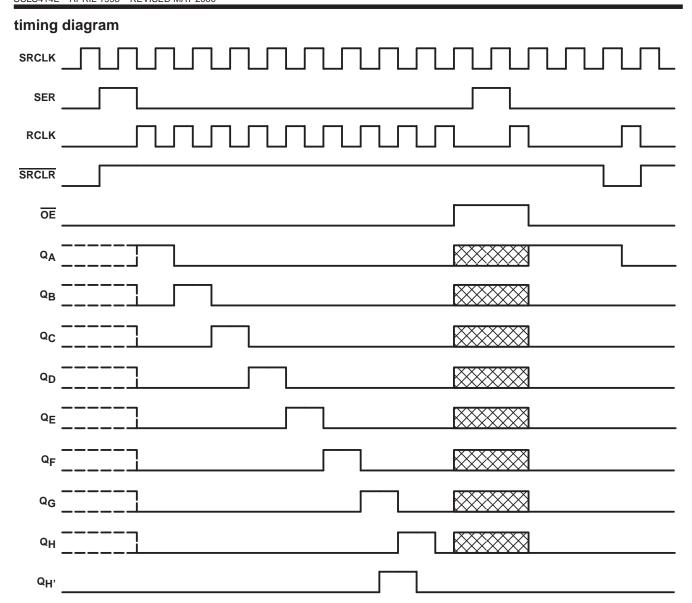
logic diagram (positive logic)



Pin numbers shown are for the D, DB, J, NS, PW, and W packages.



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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V _{CC}	0.5 V to 7 V
Input voltage range, V _I (see Note 1)	
Voltage range applied to any output in the high-impedance	
or power-off state, V _O (see Note 1)	0.5 V to 7 V
Output voltage range applied in the high or low state, V _O (see Notes 1 and 2)	0.5 V to V_{CC} + 0.5 V
Input clamp current, I _{IK} (V _I < 0)	–20 mA
Output clamp current, I _{OK} (V _O < 0 or V _O > V _{CC})	±50 mA
Continuous output current, $I_O(V_O = 0 \text{ to } V_{CC})$	±35 mA
Continuous current through V _{CC} or GND	±70 mA
Package thermal impedance, θ _{JA} (see Note 3): D package	73°C/W
DB package	82°C/W
NS package	64°C/W
PW package	108°C/W
Storage temperature range, T _{stg}	–65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.
 - 2. This value is limited to 5.5 V maximum.
 - 3. The package thermal impedance is calculated in accordance with JESD 51.



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recommended operating conditions (see Note 4)

			SN54L	.V595A	SN74I	_V595A	UNIT
			MIN	MAX	MIN	MAX	UNII
Vcc	Supply voltage		2	5.5	2	5.5	V
		V _{CC} = 2 V	1.5		1.5		
\/	High level input voltage	V _{CC} = 2.3 V to 2.7 V	V _{CC} ×0.7		V _{CC} × 0.7		V
VIH	High-level input voltage	V _{CC} = 3 V to 3.6 V	V _{CC} ×0.7		V _{CC} ×0.7		V
		V _{CC} = 4.5 V to 5.5 V	V _{CC} ×0.7		V _{CC} × 0.7		
		V _{CC} = 2 V		0.5		0.5	
١/	Low lovel input valtage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		V _{CC} ×0.3		V _{CC} ×0.3	V
VIL	Low-level input voltage	V _{CC} = 3 V to 3.6 V		V _{CC} ×0.3		V _{CC} × 0.3	V
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$		V _{CC} ×0.3		$V_{CC} \times 0.3$	
٧ _I	Input voltage	-	0	5.5	0	5.5	V
\/ -	Outrout valtage	High or low state	0	⁴ √VCC	0	VCC	V
VO	Output voltage	3-state 0 5.5 0	5.5	V			
		V _{CC} = 2 V	S	-50		-50	μΑ
lau	High-level output current	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	20	-2		-2	
ЮН	High-level output current	V _{CC} = 3 V to 3.6 V	Q	-8		-8	mA
		V _{CC} = 4.5 V to 5.5 V		-16		-16	
		V _{CC} = 2 V		50		50	μΑ
1	Love lovel output ourrest	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		2		2	
lOL	Low-level output current	V _{CC} = 3 V to 3.6 V		8		8	mA
		V _{CC} = 4.5 V to 5.5 V		16		16	
		V _{CC} = 2.3 V to 2.7 V	0	200	0	200	
$\Delta t/\Delta v$	Input transition rise or fall rate	V _{CC} = 3 V to 3.6 V	0	100	0	100	ns/V
	—	V _{CC} = 4.5 V to 5.5 V	0	20	0	20	
T _A	Operating free-air temperature	<u> </u>	-55	125	-40	85	°C

NOTE 4: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

DAD	AMETER	TEST CONDITIONS	,,	SN54	1LV595A		SN74	LV595A		UNIT
PAR	AWETER	TEST CONDITIONS	VCC	MIN	TYP	MAX	MIN	TYP	MAX	UNIT
		I _{OH} = -50 μA	2 V to 5.5 V	V _{CC} -0.1			V _{CC} -0.1			
		$I_{OH} = -2 \text{ mA}$	2.3 V	2			2			
\/a	Q _H ′	$I_{OH} = -6 \text{ mA}$	3 V	2.48			2.48			٧
VOH	Q _A –Q _H	$I_{OH} = -8 \text{ mA}$	3 V	2.48			2.48			V
	Q _H ′	I _{OH} = -12 mA	4.5 V	3.8			3.8			
	Q _A –Q _H	I _{OH} = -16 mA	4.5 V	3.8			3.8			
		I _{OL} = 50 μA	2 V to 5.5 V		F	0.1			0.1	
		I _{OL} = 2 mA	2.3 V		F	0.4			0.4	
1	$Q_{H'}$	I _{OL} = 6 mA	3 V		Q	0.44			0.44	V
VOL	Q _A –Q _H	I _{OL} = 8 mA	3 V		Ć,	0.44			0.44	V
	Q _H ′	I _{OL} = 12 mA	4.5.1/	20		0.55			0.55	
	Q _A –Q _H	I _{OL} = 16 mA	4.5 V	Q.		0.55			0.55	
lı		$V_I = V_{CC}$ or GND	0 V to 5.5 V			±1			±1	μΑ
loz		$V_O = V_{CC}$ or GND	5.5 V			±5			±5	μΑ
Icc		$V_I = V_{CC}$ or GND $I_O = 0$	5.5 V			20			20	μΑ
l _{off}		V_I or $V_O = 0$ to 5.5 V	0 V			5			5	μΑ
Ci		V _I = V _{CC} or GND	3.3 V		3.5			3.5		pF

timing requirements over recommended operating free-air temperature range, V_{CC} = 2.5 V \pm 0.2 V (unless otherwise noted) (see Figure 1)

			T _A =	25°C	SN54L	V595A	SN74L	/595A	UNIT	
			MIN	MAX	MIN	MAX	MIN	MAX	UNII	
		SRCLK high or low		7		7.5		7.5		
t _W	Pulse duration	RCLK high or low		7		7.5		7.5	ns	
		SRCLR low		6	6.5		6.5			
		SER before SRCLK↑		2.5	4	3		3		
	Catum times	SRCLK↑ before RCLK↑†		8	ζ),	9		9		
t _{su}	Setup time	SRCLR low before RCLK↑		8.5	20	9.5		9.5	ns	
		SRCLR high (inactive) before SRCLK↑		4	A)	4		4		
t _h	Hold time	SER after SRCLK↑		1.5		1.5		1.5	ns	

[†] This setup time allows the storage register to receive stable data from the shift register. The clocks can be tied together, in which case the shift register is one clock pulse ahead of the storage register.



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timing requirements over recommended operating free-air temperature range, V_{CC} = 3.3 V \pm 0.3 V (unless otherwise noted) (see Figure 1)

			T _A = 2	25°C	SN54L	V595A	SN74L\	/595A	UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	UNII
		SRCLK high or low		5.5		5.5		5.5	
t _W	Pulse duration	RCLK high or low		5.5		5.5		5.5	ns
		SRCLR low		5	5		5		
		SER before SRCLK↑		3.5	4	3.5		3.5	
١.	Catura tima	SRCLK↑ before RCLK↑†		8	ζ),	8.5		8.5	
t _{su}	Setup time	SRCLR low before RCLK↑		8	γ_{Q_i}	9		9	ns
		SRCLR high (inactive) before SRCLK↑		3) V	3		3	
th	Hold time	SER after SRCLK↑		1.5		1.5		1.5	ns

[†] This setup time allows the storage register to receive stable data from the shift register. The clocks can be tied together, in which case the shift register is one clock pulse ahead of the storage register.

timing requirements over recommended operating free-air temperature range, V_{CC} = 5 V \pm 0.5 V (unless otherwise noted) (see Figure 1)

			T _A =	25°C	SN54L	V595A	SN74L\	/595A	UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	UNIT
		SRCLK high or low		5		5		5	
t _W	Pulse duration	RCLK high or low		5		5		5	ns
		SRCLR low				5.2			
		SER before SRCLK↑		3		3		3	
١.	Onton Care	SRCLK↑ before RCLK↑†		5		5		5	
t _{su}	Setup time	SRCLR low before RCLK↑		5	20	5		5	ns
		SRCLR high (inactive) before SRCLK↑		2.5	7AC	2.5		2.5	
t _h	Hold time	SER after SRCLK↑		2		2		2	ns

[†] This setup time allows the storage register to receive stable data from the shift register. The clocks can be tied together, in which case the shift register is one clock pulse ahead of the storage register.

switching characteristics over recommended operating free-air temperature range, V_{CC} = 2.5 V \pm 0.2 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	LOAD	T,	Δ = 25°C	;	SN54L	/595A	SN74L	/595A	UNIT
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNII
· ·			C _L = 15 pF	65*	80*		45*		45		MHz
f _{max}			C _L = 50 pF	60	70		40		40		IVITIZ
t _{PLH}	BOLK	0 0			8.4*	14.2*	1*	15.8*	1	15.8	
t _{PHL}	RCLK	Q _A –Q _H			8.4*	14.2*	1*	15.8*	1	15.8	
^t PLH	SRCLK	0]		9.4*	19.6*	1*	22.2*	1	22.2	
^t PHL	SRCLK	Q _H ′]		9.4*	19.6*	1*	22.2*	1	22.2	
t _{PHL}	SRCLR	$Q_{H'}$	C _L = 15 pF		8.7*	14.6*	1*	16.3*	1	16.3	ns
^t PZH		0. 0]		8.2*	13.9*	1*	15*	1	15	
^t PZL	ŌĒ	Q _A –Q _H			10.9*	18.1*	1*	20.3*	1	20.3	
^t PHZ	<u>OE</u>	00]		8.3*	13.7*	1*,	15.6*	1	15.6	
^t PLZ	OE	Q _A –Q _H			9.2*	15.2*	15	16.7*	1	16.7	
^t PLH	RCLK	0. 0			11.2	17.2	S1	19.3	1	19.3	
^t PHL	KCLK	Q _A –Q _H]		11.2	17.2	2 1	19.3	1	19.3	
^t PLH	SRCLK	0			13.1	22.5	1	25.5	1	25.5	
^t PHL	SKCLK	Q _H ′]		13.1	22.5	1	25.5	1	25.5	
^t PHL	SRCLR	$Q_{H'}$	C _L = 50 pF		12.4	18.8	1	21.1	1	21.1	ns
^t PZH				10.8	17	1	18.3	1	18.3		
^t PZL	OE .	Q _A -Q _H]		13.4	21	1	23	1	23	
^t PHZ	ŌĒ		-	.T		12.2	18.3	1	19.5	1	19.5
^t PLZ	OL .	Q _A –Q _H			14	20.9	1	22.6	1	22.6	

^{*} On products compliant to MIL-PRF-38535, this parameter is not production tested.

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switching characteristics over recommended operating free-air temperature range, V_{CC} = 3.3 V \pm 0.3 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	LOAD	T,	4 = 25°C	;	SN54L	V595A	SN74L\	/595A	UNIT
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
f.			C _L = 15 pF	80*	120*		70*		70		MHz
f _{max}			C _L = 50 pF	55	105		50		50		IVITIZ
tPLH	DOLK				6*	11.9*	1*	13.5*	1	13.5	
t _{PHL}	RCLK	Q _A –Q _H			6*	11.9*	1*	13.5*	1	13.5	
t _{PLH}	CDCI IX	0			6.6*	13*	1*	15*	1	15	
t _{PHL}	SRCLK	$Q_{H'}$			6.6*	13*	1*	15*	1	15	
t _{PHL}	SRCLR	$Q_{H'}$	C _L = 15 pF		6.2*	12.8*	1*	13.7*	1	13.7	ns
t _{PZH}		0 - 0 -			6*	11.5*	1*	13.5*	1	13.5	
t _{PZL}	ŌĒ	Q _A –Q _H			7.8*	11.5*	1*	13.5*	1	13.5	
t _{PHZ}	ŌĒ	00			6.1*	14.7*	1*,	15.2*	1	15.2	
t _{PLZ}	OE	Q _A –Q _H			6.3*	14.7*	1	15.2*	1	15.2	
t _{PLH}	BCLK	0.0.			7.9	15.4	Q ₁	17	1	17	
^t PHL	RCLK	Q _A –Q _H			7.9	15.4	1	17	1	17	
t _{PLH}	SRCLK	0			9.2	16.5	1	18.5	1	18.5	
t _{PHL}	SRCLK	$Q_{H'}$			9.2	16.5	1	18.5	1	18.5	
t _{PHL}	SRCLR	$Q_{H'}$	C _L = 50 pF		9	16.3	1	17.2	1	17.2	ns
^t PZH	<u> </u>	OE Q _A -Q _H			7.8	15	1	17	1	17	
t _{PZL}	UE]		9.6	15	1	17	1	17	
^t PHZ	ŌĒ	04.00]		8.1	15.7	1	16.2	1	16.2	
t _{PLZ}	OE .	Q _A –Q _H			9.3	15.7	1	16.2	1	16.2	

^{*} On products compliant to MIL-PRF-38535, this parameter is not production tested.

switching characteristics over recommended operating free-air temperature range, V_{CC} = 5 V \pm 0.5 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	LOAD	T,	չ = 25°C	;	SN54L\	/595A	SN74L	/595A	UNIT
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNII
f			C _L = 15 pF	135*	170*		115*		115		MHz
fmax			C _L = 50 pF	120	140		95		95		IVITIZ
t _{PLH}	DOLK				4.3*	7.4*	1*	8.5*	1	8.5	
t _{PHL}	RCLK	Q_A-Q_H]		4.3*	7.4*	1*	8.5*	1	8.5	
t _{PLH}	000114	$Q_{H'}$]		4.5*	8.2*	1*	9.4*	1	9.4	
t _{PHL}	SRCLK	QH'			4.5*	8.2*	1*	9.4*	1	9.4	
t _{PHL}	SRCLR	Q _H ′	C _L = 15 pF		4.5*	8*	1*	9.1*	1	9.1	ns
^t PZH]		4.3*	8.6*	1*	10*	1	10	
t _{PZL}	ŌĒ	Q_A-Q_H			5.4*	8.6*	1*	10*	1	10	
t _{PHZ}	ŌĒ]		2.4*	6*	1*,	7.1*	1	7.1	
tPLZ	OE	Q _A –Q _H			2.7*	5.1*	1*	7.2*	1	7.2	
t _{PLH}	DOLK	0 0			5.6	9.4	Q ₁	10.5	1	10.5	
t _{PHL}	RCLK	Q_A-Q_H			5.6	9.4	1	10.5	1	10.5	
t _{PLH}	SDCI K	0]		6.4	10.2	1	11.4	1	11.4	
t _{PHL}	SRCLK	$Q_{H'}$]		6.4	10.2	1	11.4	1	11.4	
t _{PHL}	SRCLR QH' ○E QA-QH ○E QA-QH	C _L = 50 pF		6.4	10	1	11.1	1	11.1	ns	
^t PZH		0 0]		5.7	10.6	1	12	1	12	
^t PZL		QA−QH]		6.8	10.6	1	12	1	12	
t _{PHZ}]		3.5	10.3	1	11	1	11		
t _{PLZ}	OE .	Q _A –Q _H			3.4	10.3	1	11	1	11	

^{*} On products compliant to MIL-PRF-38535, this parameter is not production tested.

noise characteristics, V_{CC} = 3.3 V, C_L = 50 pF, T_A = 25°C (see Note 5)

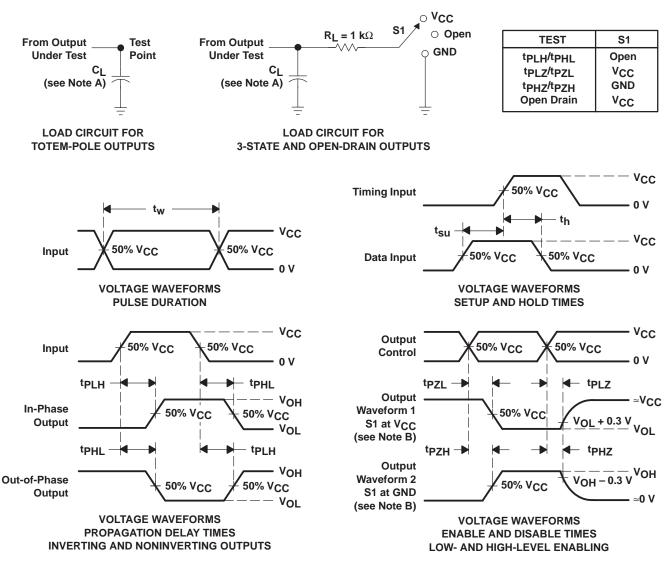
	PARAMETER	SN	SN74LV595A			
	PARAMETER	MIN	TYP	MAX	UNIT	
V _{OL(P)}	Quiet output, maximum dynamic V _{OL}		0.3		V	
V _{OL(V)}	Quiet output, minimum dynamic V _{OL}		-0.2		V	
VOH(V)	Quiet output, minimum dynamic VOH		2.8		V	
VIH(D)	High-level dynamic input voltage	2.31			V	
V _{IL(D)}	Low-level dynamic input voltage			0.99	V	

NOTE 5: Characteristics are for surface-mount packages only.

operating characteristics, $T_A = 25^{\circ}C$

	PARAMETER	TEST CO	VCC	TYP	UNIT	
C	Power dissipation capacitance	$C_1 = 50 pF$	f = 10 MHz	3.3 V	111	pF
Cpd	Tower dissipation capacitance	$C_L = 50 \text{ pF},$	1 - 10 101112	5 V	114	ρi

PARAMETER MEASUREMENT INFORMATION



- NOTES: A. C_I includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, $Z_O = 50 \Omega$, $t_f \leq 3$ ns, $t_f \leq 3$ ns.
 - D. The outputs are measured one at a time with one input transition per measurement.
 - E. tpl 7 and tpH7 are the same as tdis.
 - F. tpzL and tpzH are the same as ten.
 - G. tpHL and tpLH are the same as tpd.

Figure 1. Load Circuit and Voltage Waveforms



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